T.	Hits	Search Text	155	
Number			DB	Time stamp
2	359	((metal near insulator near transistor) (MIS near transistor)) and (trench\$2 recess\$2)	USPAT; US-PGPUB; EPO; JPO;	2004/05/06
•	71441	electric near charge	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/05/06
	46	(((metal near insulator near transistor) (MIS near transistor)) and (trench\$2	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/05/06 09:41
		recess\$2)) and (electric near charge)	EPO; JPO; DERWENT; IBM TDB	09.41

L Number	Hits	Search Text	DB	Time stamp
7	1219 3158455	nitride)) (silicon near oxide/silicon near nitride/silicon near oxide) (oxide/nitride/oxide) (oxide-nitride-oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/06
8	535	((((silicon near oxide) and (silicon near nitride)) (silicon near oxide/silicon near nitride/silicon near oxide) (oxide/nitride/oxide) (oxide-nitride-oxide) ONO) with charge) and (trench\$2 recess\$2 opening)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/06 10:01 2004/05/06 10:02

umber	Hits	Search Text	DB	Time stamp
3	7180	metal many days		- Lane Beamp
,	7100	metal near insulator near semiconductor) (metal-insulator near semiconductor) (MIS near2 transistor	USPAT; US-PGPUB; EPO; JPO;	2004/05/06
4	3795257	trench\$2 recess\$2 opening groove	DERWENT; IBM_TDB USPAT;	2004/05/06
			US-PGPUB; EPO; JPO; DERWENT;	11:21
6	135958	<pre>(((silicon near oxide) and (silicon near nitride)) (silicon near oxide/silicon near nitride/silicon near oxide) (oxide/nitride/oxide)</pre>	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/05/06 11:24
7	942	(oxide-nitride-oxide) ONO) (metal near insulator near semiconductor) (metal-insulator near semiconductor) (Mag	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/05/06 11:25
·		near2 transistor) and (trench\$2 recess\$2 opening groove) and ((((silicon near oxide) and (silicon near nitride)) (silicon near oxide/silicon near oxide) (oxide/nitride/oxide) (oxide-nitride-oxide) (NO))	EPO; JPO; DERWENT; IBM_TDB	